

QUARTZ CRYSTAL OSCILLATOR

■ GENERAL DESCRIPTION

The NJU6361A is a C-MOS quartz crystal oscillator which consists of an oscillation amplifier, 3-stage divider, output frequency selector and inverter output buffer.

The oscillation frequency is as wide as up to 50MHz and the symmetry of 45-55% is realized over full oscillation frequency range.

The oscillation amplifier incorporates feed-back resistance and oscillation capacitors(C_g , C_d), therefore, it requires no external component except quartz crystal.

The 3-stage divider outputs f_o , $f_o/2$, $f_o/4$ and $f_o/8$ to the output frequency selector and it determined one output frequency according to the combination of two input-signal.

The inverter output buffer is C-MOS compatible and capable of 10 LSTTL driving.

4

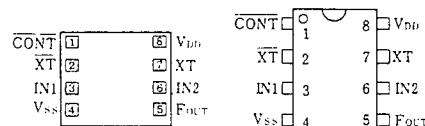
■ PACKAGE OUTLINE



NJU6361AC

NJU6361AE

■ PIN CONFIGURATION/PAD LOCATION



■ FEATURES

- Operating Voltage -- 3.0~6.0V
- Maximum Oscillation Frequency -- 50MHz
- Low Operating Current
- High Fan-out -- LSTTL 10
- Inverter Output Buffer
- Selected Frequency Output
Only one frequency out of f_o , $f_o/2$, $f_o/4$ and $f_o/8$ output
- Oscillation Capacitors C_g and C_d on-chip
- Oscillation and Output Stand-by Function
- Package Outline -- CHIP/EMP 8
- C-MOS Technology

■ COORDINATES

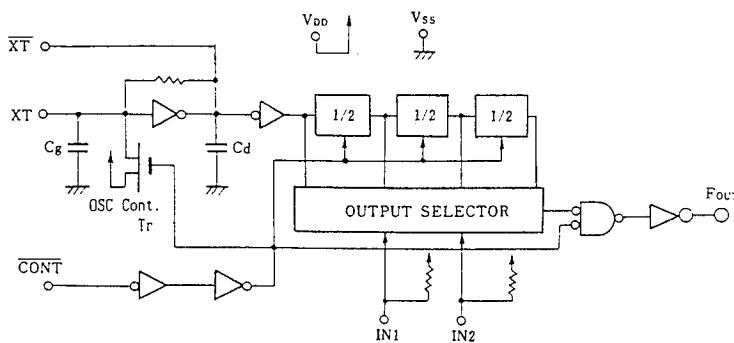
Unit: μm

No.	PAD	X	Y
1	CONT	165	651
2	XT	165	484
3	IN1	165	317
4	V _{SS}	165	149
5	F _{OUT}	1113	149
6	IN2	1113	317
7	XT	1113	484
8	V _{DD}	1113	651

Chip Size : 1.28 X 0.8mm

Chip Thickness : 400 $\mu\text{m} \pm 30 \mu\text{m}$

■ BLOCK DIAGRAM



■ TERMINAL DESCRIPTION

NO.	SYMBOL	FUNCTION	
1	CONT	Oscillation Stop Control and Divider Reset	
		CONT F_{OUT}	
		H Output either one frequency from f_0 , $f_0/2$, $f_0/4$, and $f_0/8$	
		L Oscillation stop and Divider Reset	
2	XT	Quartz Crystal Connecting Terminals	
7	XT		
8	V _{DD}	+ 5V	
3	IN1	3-State Divider Outputs selected by IN1 and IN2	
		IN1 IN2 F_{OUT}	
		H H f_0 L H $f_0/2$ H L $f_0/4$ L L $f_0/8$	
5	F _{OUT}	Output either one frequency from f_0 , $f_0/2$, $f_0/4$, and $f_0/8$	
4	V _{SS}	GND	

4

■ ABSOLUTE MAXIMUM RATINGS

(Ta=25°C)

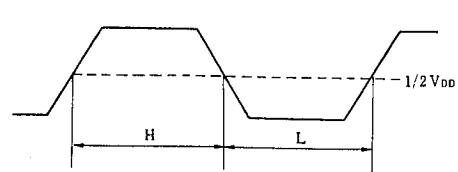
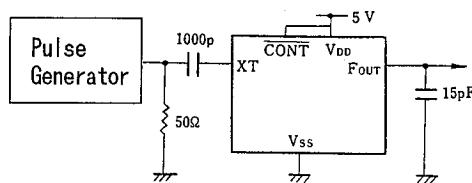
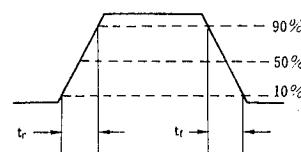
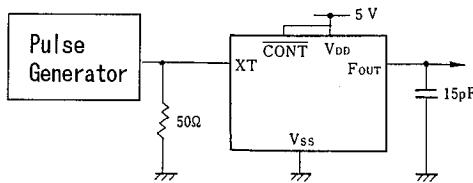
P A R A M E T E R	S Y M B O L	R A T I N G S	U N I T
Supply Voltage	V _{DD}	-0.5 ~ +7.0	V
Input Voltage	V _{IN}	-0.5 ~ V _{DD} +0.5	V
Output Voltage	V _O	-0.5 ~ V _{DD} +0.5	V
Input Current	I _{IN}	±10	mA
Output Current	I _O	±25	mA
Power Dissipation (EMP)	P _D	200	mW
Operating Temperature Range	T _{OPR}	-40 ~ + 85	°C
Storage Temperature Range	T _{STG}	-65 ~ +150	°C

■ ELECTRICAL CHARACTERISTICS

(Ta=25°C, V_{DD}=5V)

P A R A M E T E R	S Y M B O L	C O N D I T I O N S	M I N	T Y P	M A X	U N I T
Operating Voltage	V _{DD}		3		6	V
Operating Current	I _{DD}	fosc=16MHz, No load			10	mA
Stand-by Current	I _{ST}	CONT, XT=V _{SS} , No load (Note)			1	μA
Input Voltage	V _{IH}		3.5		5.0	
	V _{IL}		0		1.5	V
Output Current	I _{OH}	V _{DD} =5V, V _{OH} =4.5V	4			
	I _{OL}	V _{DD} =5V, V _{OL} =0.5V	4			mA
Input Current	I _{IN}	CONT, IN1, IN2 Terminals CONT, IN1, IN2=V _{SS}			400	μA
Internal Capacitor	C _g	A Version		21		
	C _d	A Version		23		pF
	C _{g,Cd}	P Version		-		
Max. Oscillation Freq.	f _{MAX}	V _{DD} =5V, C _L =15pF	50			MHz
Output Signal Symmetry	SYM	V _{DD} =5V, C _L =15pF at 1/2V _{DD}	45	50	55	%
Output Signal Rise Time	t _r	V _{DD} =5V, C _L =15pF, 10% - 90%			8	ns
Output Signal Fall Time	t _f	V _{DD} =5V, C _L =15pF, 90% - 10%			8	ns

Note) Excluding input current on CONT terminal.

■ MEASUREMENT CIRCUITS(1) Output Signal Symmetry ($C_L=15\text{pF}$)(2) Output Signal Rise/Fall Time ($C_L=15\text{pF}$)

MEMO

[CAUTION]

The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.